

**HEX D-TYPE FLIP FLOP WITH CLEAR**

The TC74ACT174 is an advanced high speed CMOS HEX D-TYPE FLIP FLOP fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the CLR input is held low, the Q output are in the low logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

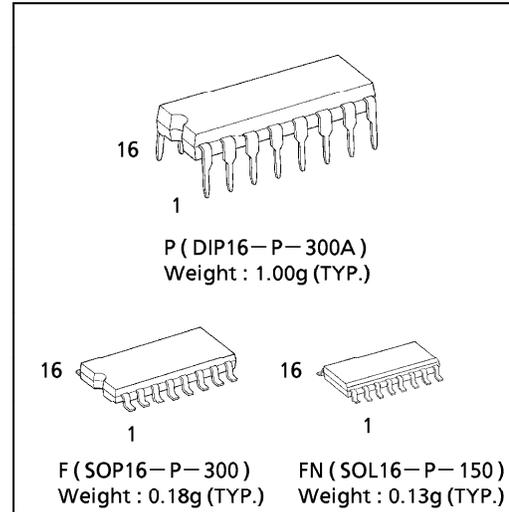
**FEATURES :**

- High Speed..... $f_{MAX} = 155\text{MHz}(\text{typ.})$   
at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 8\mu\text{A}(\text{Max.})$  at  $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs.... $V_{IL} = 0.8\text{V}(\text{Max.})$   
 $V_{IH} = 2.0\text{V}(\text{Min.})$
- Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 24\text{mA}(\text{Min.})$   
Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays.... $t_{pLH} \approx t_{pHL}$
- Pin and Function Compatible with 74F174

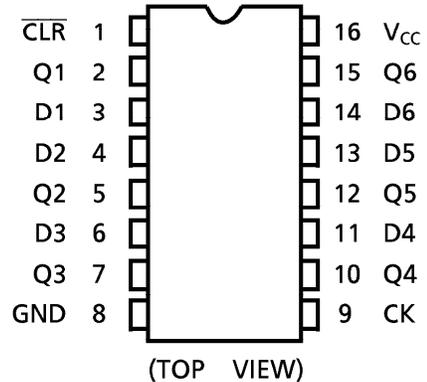
**TRUTH TABLE**

INPUTS			OUTPUTS	FUNCTION
CLR	D	CK	Q	
L	X	X	L	CLEAR
H	L		L	—
H	H		H	—
H	X		Q <sub>n</sub>	NO CHANGE

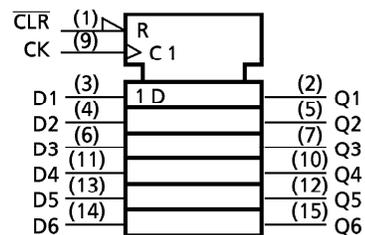
X : Don't Care



**PIN ASSIGNMENT**



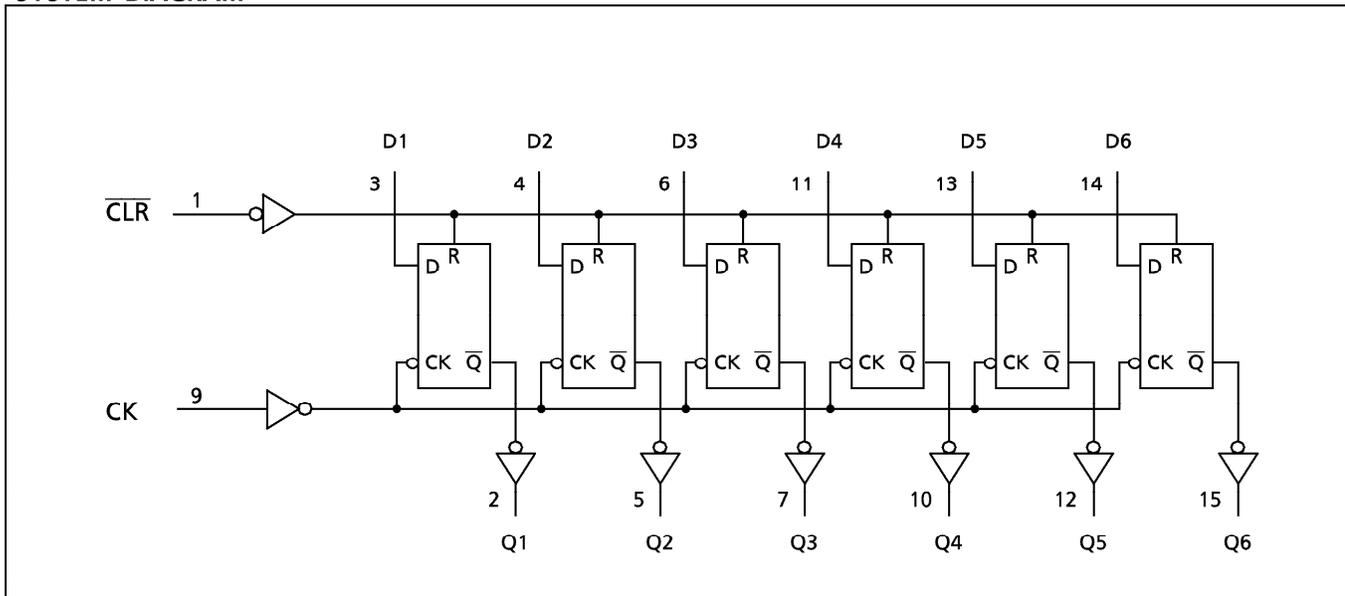
**IEC LOGIC SYMBOL**



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**SYSTEM DIAGRAM**



**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC} + 0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 50$	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 150$	mA
Power Dissipation	$P_D$	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	-65~150	°C

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  should be applied up to 300mW.

**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	4.5~5.5	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$dt/dV$	0~10	ns/V

**DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION		V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V <sub>IH</sub>			4.5 } 5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V <sub>IL</sub>			4.5 } 5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50μA	4.5	4.4	4.5	—	4.4	—	V
			I <sub>OH</sub> = -24mA	4.5	3.94	—	—	3.80	—	
			I <sub>OH</sub> = -75mA*	5.5	—	—	—	3.85	—	
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I <sub>OL</sub> = 24mA	4.5	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 75mA*	5.5	—	—	—	—	1.65	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	8.0	—	80.0	
	I <sub>C</sub>	PER INPUT : V <sub>IN</sub> = 3.4V OTHER INPUT : V <sub>CC</sub> or GND		5.5	—	—	1.35	—	1.5	mA

\* : This spec indicates the capability of driving 50Ω transmission lines.  
One output should be tested at a time for a 10ms maximum duration.

**TIMING REQUIREMENTS (Input t<sub>r</sub> = t<sub>f</sub> = 3ns)**

PARAMETER	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	Ta = 25°C	Ta = -40~85°C	UNIT
				LIMIT	LIMIT	
Minimum Pulse Width (CK)	t <sub>W(L)</sub>		5.0 ± 0.5	5.0	5.0	ns
	t <sub>W(H)</sub>					
Minimum Pulse Width (CLR)	t <sub>W(L)</sub>		5.0 ± 0.5	5.0	5.0	
Minimum Set - up Time	t <sub>s</sub>		5.0 ± 0.5	3.5	3.5	
Minimum Hold Time	t <sub>h</sub>		5.0 ± 0.5	2.0	2.0	
Minimum Removal Time (CLR)	t <sub>rem</sub>		5.0 ± 0.5	3.0	3.0	

**AC ELECTRICAL CHARACTERISTICS (C<sub>L</sub> = 50pF, R<sub>L</sub> = 500 Ω, Input t<sub>r</sub> = t<sub>f</sub> = 3ns)**

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C		UNIT	
			V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	MIN.		MAX.
Propagation Delay Time (CK-Q)	t <sub>pLH</sub> t <sub>pHL</sub>		5.0 ± 0.5	—	7.1	10.1	1.0	11.5	ns
Propagation Delay Time ( $\overline{\text{CLR}}$ -Q)	t <sub>pHL</sub>		5.0 ± 0.5	—	7.4	11.8	1.0	13.5	
Maximum Clock Frequency	f <sub>MAX</sub>		5.0 ± 0.5	85	140	—	85	—	MHz
Input Capacitance	C <sub>IN</sub>			—	5	10	—	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (1)			—	32	—	—	—	

Note(1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

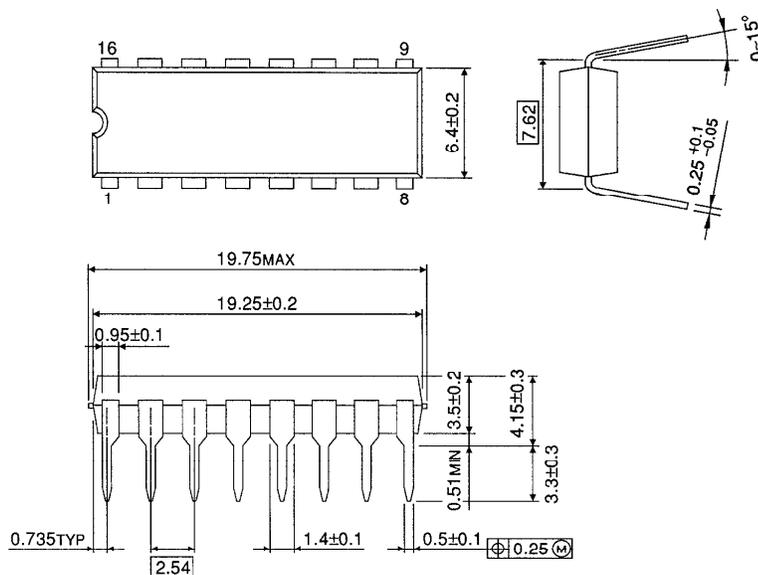
$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6 \text{ (per F/F)}$$

And the total C<sub>PD</sub> when n pcs of Flip Flop operate can be gained by the following equation.

$$C_{PD} \text{ (total)} = 20 + 12 \cdot n$$

**DIP 16PIN OUTLINE DRAWING (DIP16-P-300A)**

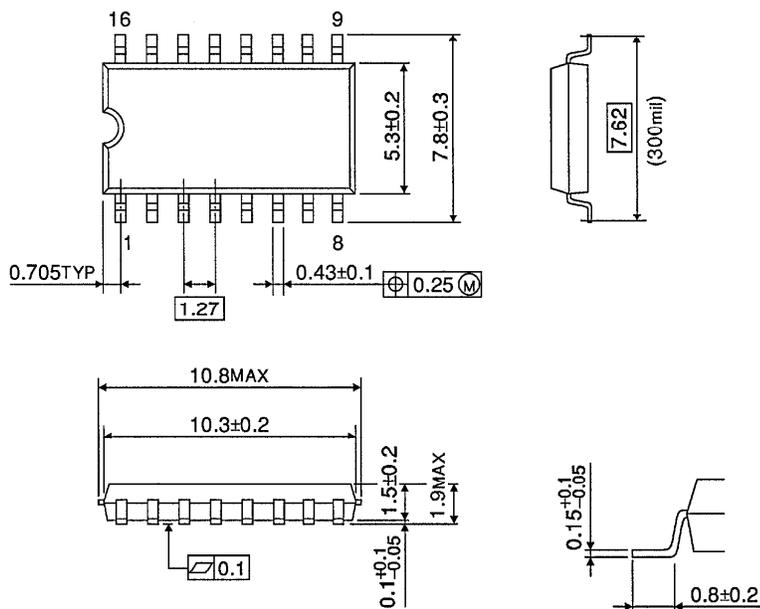
Unit in mm



Weight : 1.00g (TYP.)

**SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300)**

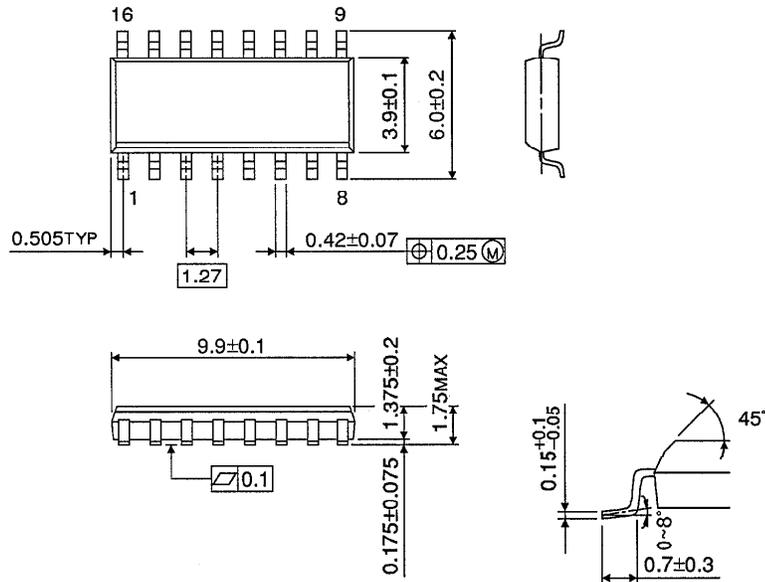
Unit in mm



Weight : 0.18g (TYP.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150)

Unit in mm



Weight : 0.13g (TYP.)